

EPO-TEK® H20E-LV Technical Data Sheet

For Reference Only

Electrically Conductive, Silver Epoxy

Number of Components: Two Minimum Bond Line Cure Schedule*:

Mix Ratio By Weight:1:1175°C45 SecondsSpecific Gravity:150°C5 MinutesPart A1.93120°C15 Minutes

Part B 3.07 80°C 3 Hours
Pot Life: 3 Days

Shelf Life: One year at room temperature

Note: Container(s) should be kept closed when not in use. For filled systems, mix contents of each container (A & B) thoroughly before mixing the two together. *Please see Applications Note available on our website.

Product Description:

EPO-TEK® H20E-LV is a two component, 100% solids silver-filled epoxy system designed specifically for chip bonding in microelectronic and optoelectronic applications. It is a low viscosity version of EPO-TEK® H20E, semiconductor die-attach epoxy.

EPO-TEK® H20E-LV Advantages & Application Notes:

- Especially recommended for use in high speed chip bonding systems where very fast cures are desired.
- Suggested for JEDEC Level III and II for plastic IC packaging.
- Capable of resisting TC wire bonding temperatures in the range of 300°C to 400°C.
- Ease of use: apply by dispensing, screen printing, die-stamping or by hand.
- Especially suited for high power devices and high current flow. High power LEDs.
- Opto-electronic packaging material: LED, LCDs and fiber components.

<u>Typical Properties</u>: (To be used as a guide only, not as a specification. Data below is not guaranteed. Different batches, conditions and applications yield differing results; Cure condition: 150°C/1 hour; * denotes test on lot acceptance basis)

Physical Properties:

*Color: Part A: Silver Part B: Silver

*Consistency: Smooth flowing paste

*Viscosity (@ 100 RPM/23°C): 1,800 – 2,800 cPs

Thixotropic Index: 3.43

Weight Loss:

@ 200°C:

@ 250°C:

@ 300°C: 2.34%

*Glass Transition Temp.(Tg): ≥ 80°C (Dynamic Cure Operating Temp:

20—200°C /ISO 25 Min; Ramp -10—200°C @ 20°C/Min) Continuous: - 55°C to 200°C

Coefficient of Thermal Expansion (CTE): Intermittent: - 55°C to 300°C

 Below Tg:
 26 x 10⁻⁶ in/in/°C
 Storage Modulus @ 23°C:
 640,479 psi

 Above Tg:
 93 x 10⁻⁶ in/in/°C
 Ions:
 Cl 102 ppm

Shore D Hardness: 86 Na⁺ 98 ppm Lap Shear Strength @ 23°C: 1,500 psi NH₄⁺ 320 ppm Die Shear Strength @ 23°C: ≥ 5 Kg / 1,700 psi K⁺ 25 ppm Degradation Temp. (TGA): 400°C *Particle Size: ≤ 45 Microns

Electrical Properties:

*Volume Resistivity @ 23°C: ≤ 0.0004 Ohm-cm
Thermal Properties:

Thermal Conductivity: 2.5 W/mK

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